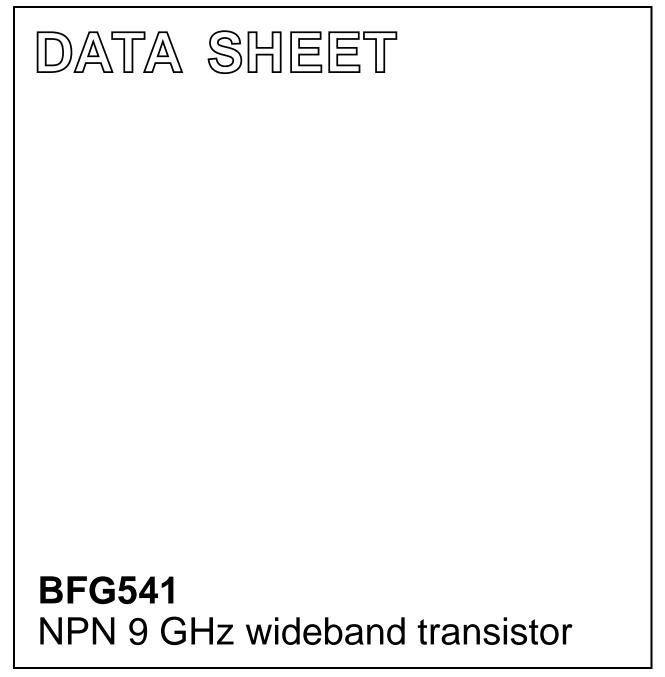
DISCRETE SEMICONDUCTORS



Product specification

September 1995



FEATURES

• High power gain

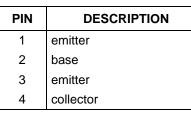
- Low noise figure
- High transition frequencyGold metallization ensures
- Gold metallization ensures excellent reliability.

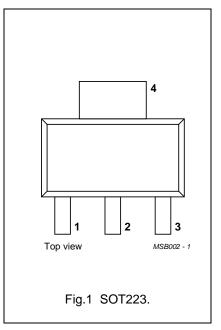
DESCRIPTION

NPN silicon planar epitaxial transistor, intended for wideband applications in the GHz range, such as analog and digital cellular telephones, cordless telephones (CT1, CT2, DECT, etc.), radar detectors, satellite TV tuners (SATV), MATV/CATV amplifiers and repeater amplifiers in fibre-optic systems.

The transistors are mounted in a plastic SOT223 envelope.

PINNING





BFG541

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-	20	V
V _{CES}	collector-emitter voltage	R _{BE} = 0	-	-	15	V
I _C	DC collector current		-	-	120	mA
P _{tot}	total power dissipation	up to T _s = 140 °C; note 1	-	-	650	mW
h _{FE}	DC current gain	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; T_{j} = 25 \text{ °C}$	60	120	250	
C _{re}	feedback capacitance	I _C = 0; V _{CB} = 8 V; f = 1 MHz	-	0.7	-	pF
f _T	transition frequency	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	-	9	-	GHz
G _{UM}	maximum unilateral power gain	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$	-	15	-	dB
		$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 2 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	-	9	-	dB
S ₂₁ ²	insertion power gain	I_{C} = 40 mA; V _{CE} = 8 V; f = 900 MHz; T _{amb} = 25 °C	13	14	-	dB
F	noise figure	$\Gamma_{s} = \Gamma_{opt}$; I _C = 10 mA; V _{CE} = 8 V; f = 900 MHz; T _{amb} = 25 °C	_	1.3	1.8	dB
P _{L1}	output power at 1 dB gain compression	I_{C} = 40 mA; V _{CE} = 8 V; R _L = 50 Ω; f = 900 MHz; T _{amb} = 25 °C	-	21	-	dBm
ITO	third order intercept point	$ I_{C} = 40 \text{ mA}; \text{ V}_{CE} = 8 \text{ V}; \text{ R}_{L} = 50 \Omega; \\ f = 900 \text{ MHz}; \text{ T}_{amb} = 25 ^{\circ}\text{C} $	_	34	-	dBm

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	20	V
V _{CES}	collector-emitter voltage	R _{BE} = 0	-	15	V
V _{EBO}	emitter-base voltage	open collector	-	2.5	V
I _C	DC collector current		_	120	mA
P _{tot}	total power dissipation	up to $T_s = 140 \text{ °C}$; note 1	_	650	mW
T _{stg}	storage temperature		-65	150	°C
Tj	junction temperature		-	175	°C

THERMAL RESISTANCE

SYMBOL	PARAMETER	CONDITIONS	THERMAL RESISTANCE
R _{th j-s}	thermal resistance from junction to soldering point	up to $T_s = 140 \text{ °C}$; note 1	55 K/W

Note

1. T_s is the temperature at the soldering point of the collector tab.

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CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 8 V	-	-	50	nA
h _{FE}	DC current gain	I _C = 40 mA; V _{CE} = 8 V	60	120	250	
C _e	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = 0.5 V; f = 1 MHz$	-	2	_	pF
C _c	collector capacitance	I _E = i _e = 0; V _{CB} = 8 V; f = 1 MHz	-	1	-	pF
C _{re}	feedback capacitance	$I_{C} = 0; V_{CB} = 8 V; f = 1 MHz$	-	0.7	_	pF
f _T	transition frequency	I_{C} = 40 mA; V_{CE} = 8 V; f = 1 GHz; T _{amb} = 25 °C	-	9	-	GHz
G _{UM}	maximum unilateral power gain (note 1)	I_{C} = 40 mA; V _{CE} = 8 V; f = 900 MHz; T _{amb} = 25 °C	-	15	-	dB
		I_{C} = 40 mA; V _{CE} = 8 V; f = 2 GHz; T _{amb} = 25 °C	-	9	_	dB
S ₂₁ ²	insertion power gain	$I_c = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 ^{\circ}\text{C}$	13	14	_	dB
F	noise figure	$\Gamma_{s} = \Gamma_{opt}$; I _C = 10 mA; V _{CE} = 8 V; f = 900 MHz; T _{amb} = 25 °C	-	1.3	1.8	dB
		$\Gamma_{s} = \Gamma_{opt}$; I _C = 40 mA; V _{CE} = 8 V; f = 900 MHz; T _{amb} = 25 °C	-	1.9	2.4	dB
		$\Gamma_{s} = \Gamma_{opt}$; I _C = 10 mA; V _{CE} = 8 V; f = 2 GHz; T _{amb} = 25 °C	-	2.1	-	dB
P _{L1}	output power at 1 dB gain compression	I_c = 40 mA; V _{CE} = 8 V; R _L = 50 Ω; f = 900 MHz; T _{amb} = 25 °C	-	21	-	dBm
ITO	third order intercept point	note 2	-	34	-	dBm
Vo	output voltage	note 3	-	500	-	mV
d ₂	second order intermodulation distortion	note 4	-	-50	-	dB

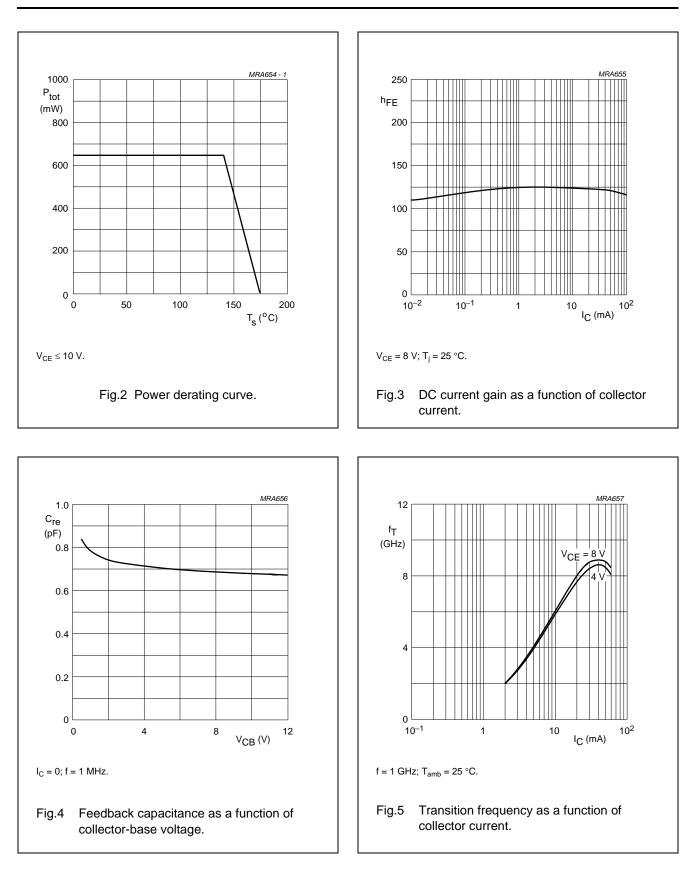
Notes

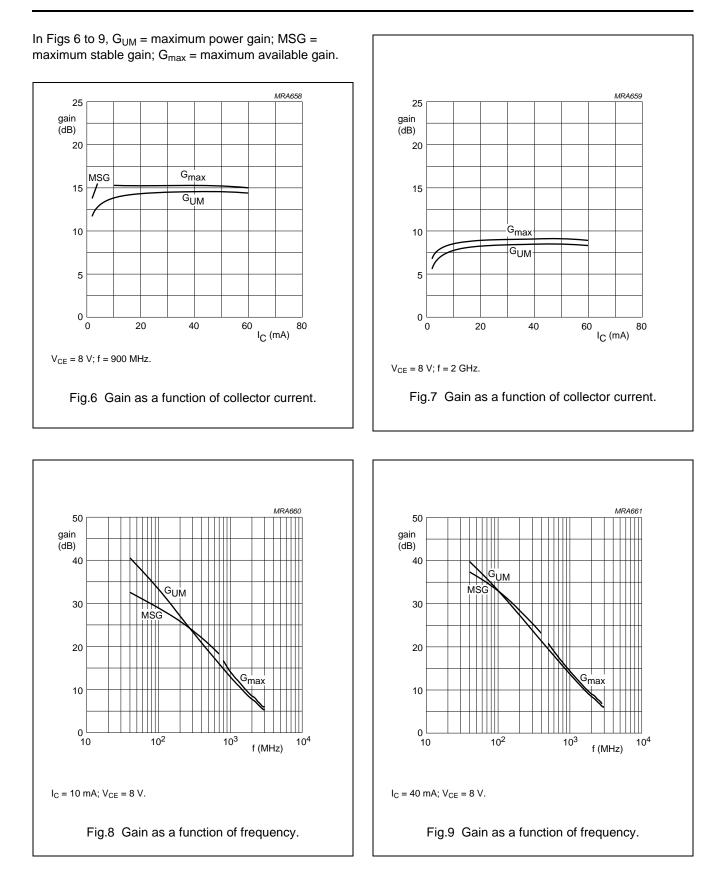
1. G_{UM} is the maximum unilateral power gain, assuming S_{12} is zero and

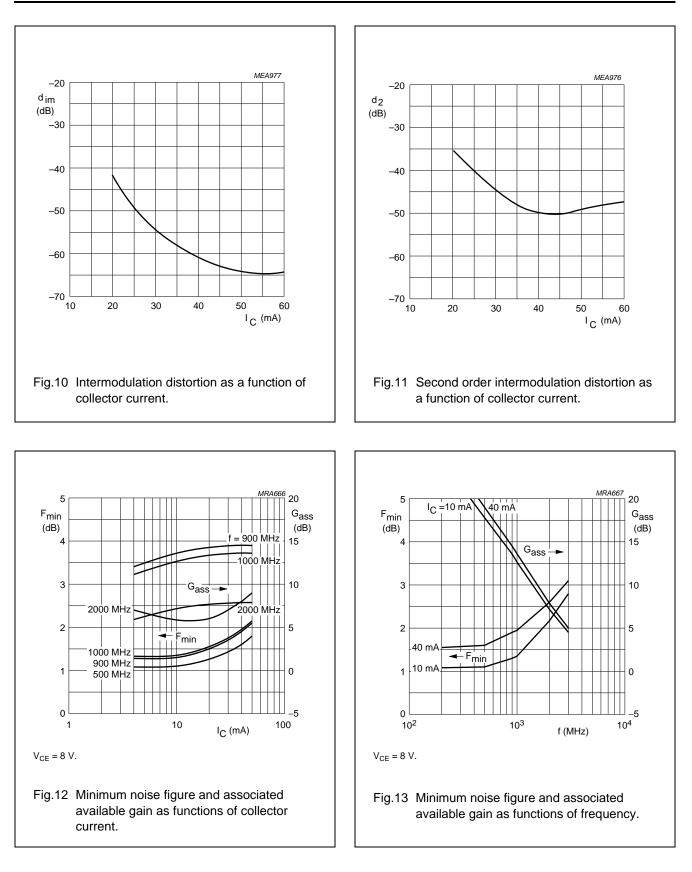
$$G_{UM} = 10 \ \text{log} \ \frac{\left|S_{21}\right|^2}{(1 - \left|S_{11}\right|^2)(1 - \left|S_{22}\right|^2)} \ \text{dB}.$$

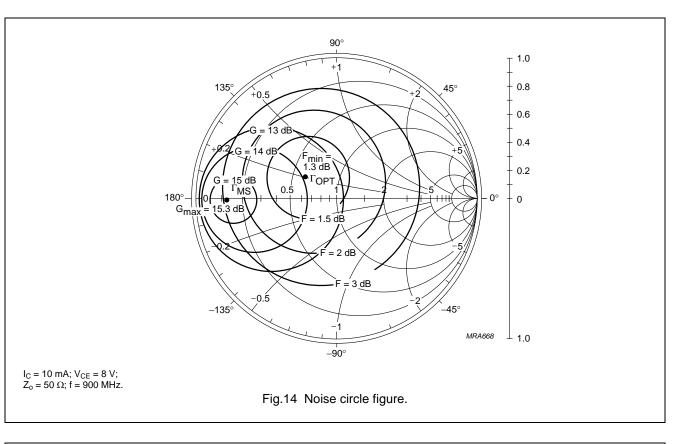
- $\begin{array}{ll} \text{2.} & I_{C} = 40 \text{ mA; } V_{CE} = 8 \text{ V; } R_{L} = 50 \ \Omega; \ f = 900 \text{ MHz; } T_{amb} = 25 \ ^{\circ}\text{C;} \\ & f_{p} = 900 \text{ MHz; } f_{q} = 902 \text{ MHz;} \\ & \text{measured at } f_{(2p-q)} = 898 \text{ MHz and at } f_{(2p-q)} = 904 \text{ MHz.} \end{array}$
- 3. $d_{im} = -60 \text{ dB} \text{ (DIN 45004B)}; I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}; Z_L = Z_s = 75 \Omega; T_{amb} = 25 \text{ °C};$ $V_p = V_0; V_q = V_0 - 6 \text{ dB}; V_r = V_0 - 6 \text{ dB};$ $f_p = 795.25 \text{ MHz}; f_q = 803.25 \text{ MHz}; f_r = 805.25 \text{ MHz};$ measured at $f_{(p+q-r)} = 793.25 \text{ MHz}$
- 4. $I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}; V_o = 325 \text{ mV}; T_{amb} = 25 \text{ °C}; f_p = 250 \text{ MHz}; f_q = 560 \text{ MHz}; measured at f_{(p+q)} = 810 \text{ MHz}$

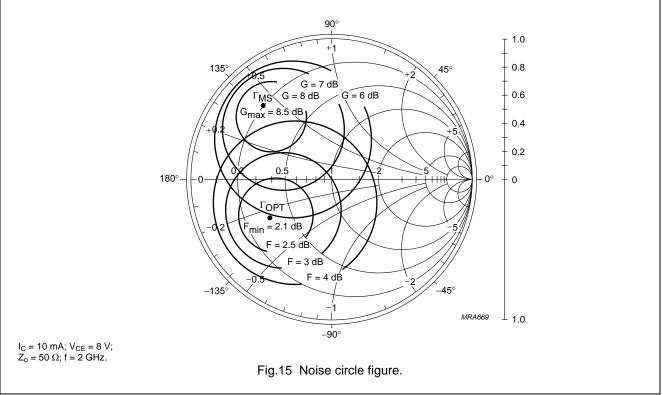
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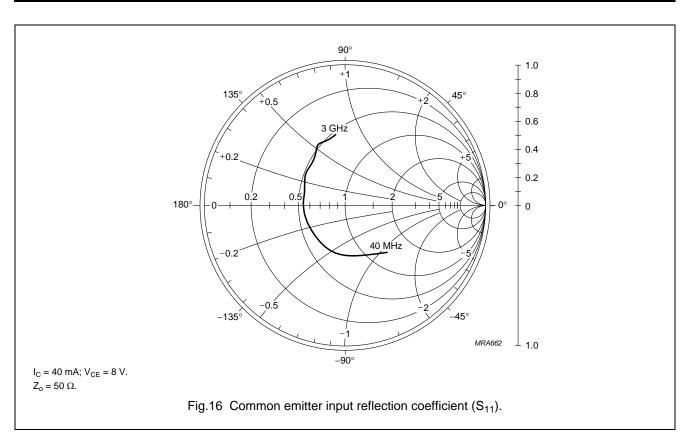


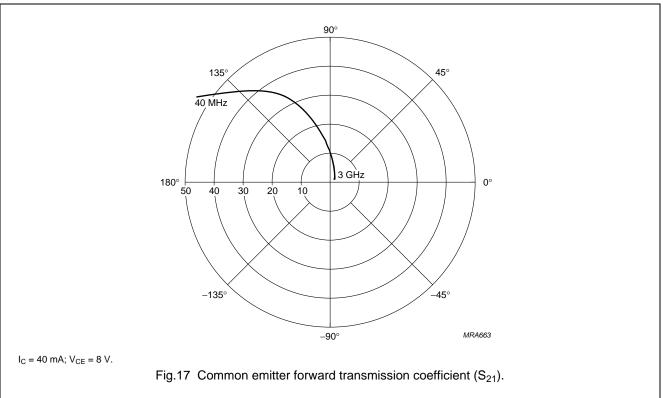


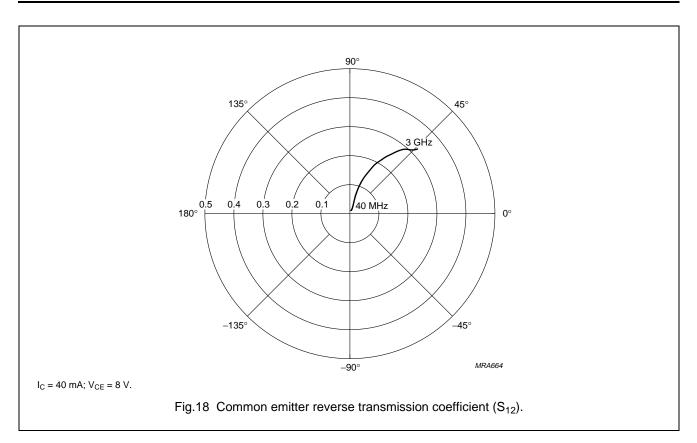


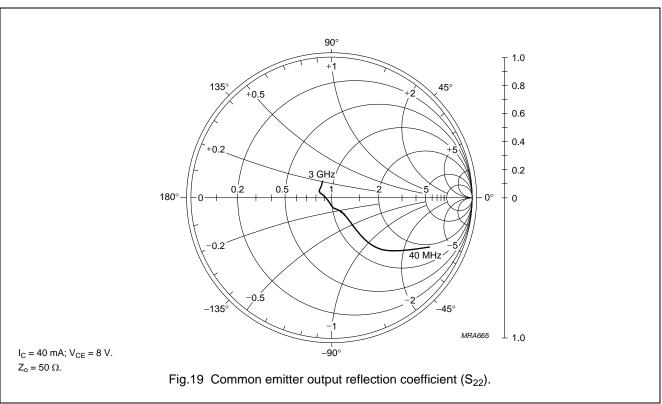




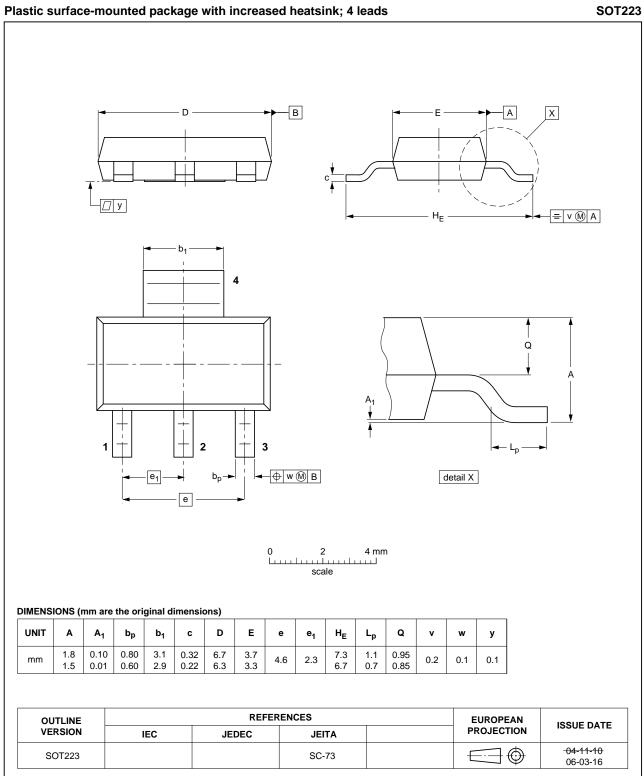








PACKAGE OUTLINE



BFG541

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Customer notification

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Contact information

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